INFORMATION

PRODUCT No.: X1E000251000800

MODEL: FA-118T

INFO. No.: A13-798-1B

Nov. 26. 2013

SEIKO EPSON CORPORATION

8548 Naka-minowa Minowa-machi Kamiina-gun Nagano-ken 399-4696 Japan

INTRODUCTION

- 1. The contents is subject to change without notice. Please exchange the specification sheets regarding the product's warranty.
- 2. This sheet is not intended to guarantee or provide an approval of implementation of industrial patents.
- 3. We have prepared this sheet as carefully as possible. If you find it incomplete or unsatisfactory in any respect, We would welcome your comments.

This product is compliant with RoHS Directive.

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Making available such products and technology to any third party who may use such products or tech nologies for the said purposes are also prohibited.

This product listed here is designed as components or parts for electronics equipment in general consumer use. We do not expect that any of these products would be incorporated or otherwise used as a component or part for the equipment, which requires an extra high reliability, such as satellite, rocket and other space systems, and medical equipment, the functional purpose of which is to keep life.

Product No. / Model

The product No. of this crystal unit is X1E000251000800.

The model is FA-118T.

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MSL

MSL level 1

[1] Absolute maximum ratings

No.	Parameter	Rating value	Note
1	Storage temperature	-40 °C to +125 °C	Suppose to be within CI std. at +25 °C ± 3 °C

[2] Operating range

	_			Value	
No.	Parameter	Symbol	Min.	Typ.	Max.
1	Operating temperature	T_use	-30 °C	_	+85 °C
2	Drive level	DL	10 μW	_	100 μW

[3] Electrical characteristics

No.	Parameter	Symbol	Standard	Conditions
1	Nominal frequency	fo	37.4 MHz	Fundamental
2	Frequency tolerance	f_tol	$\pm 10 \times 10^{-6}$	CL= 16 pF T_use = +25 °C±3 °C Drive level : 100 μW Not include aging
3	Motional resistance	R1	60 Ω Max.	π circuit JIS C6701 Drive level : 100 μW T_use= -30 °C to +85 °C
4	Shunt capacitance	C ₀	3.0 pF Max.	
5	Frequency versus temperature characteristics	f_tem	$\pm 10\times 10^{-6}$	T_use = -30 °C to +85 °C (Ref. at +25 °C±3 °C) Drive level : 100 μW
6	Isolation resistance	IR	$500~\mathrm{M}\Omega$ Min.	DC 100V × 60 sec. Between each terminals
7	Aging	f_age	$\pm 1 \times 10^{-6}$ /year	T_use = +25 °C±3 °C Drive level : 100 μW

[4] Environmental and mechanical characteristics

Item No.3 to No.6 shall be tested after following pre conditioning.

Pre conditioning: Test crystal must be leaving in room temperature for 24 h after reflow \times 3.

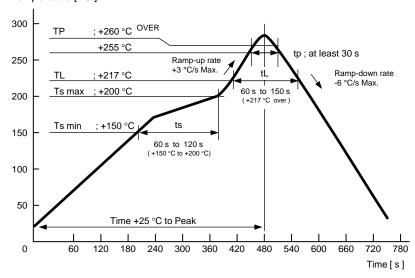
(The company evaluation condition: We evaluate it by the following examination item and examination condition.)

No.		Value *1 *2	Test Conditions
NO.	Item	$\Delta f / f [1 \times 10^{-6}]$	Test Conditions
1	Drop	*3 ±2	150 g dummy Jig (SE Standard) drop
			from 1500 mm height on the Concrete 6
			directions 10 times
2	Vibration	*3 ±2	10 Hz to 55 Hz amplitude 0.75 mm
			55 Hz to 500 Hz acceleration 98 m/s ²
			$10 \text{ Hz} \rightarrow 500 \text{ Hz} \rightarrow 10 \text{ Hz} 15 \text{ min./cycle}$
			6 h (2 hours, 3 directions)
3	High temperature storage	*3 ±2	+85 °C × 1 000 h
4	Low temperature storage	*3 ±2	-40 °C × 1 000 h
5	Temperature cycle	*3 ±2	-40 °C ↔ +85 °C
			30 minutes at each temp. 100 cycle
6	Temperature humidity	*3 ±2	+85 °C × 85 %RH × 1 000 h
	storage		
7	Resistance to soldering heat	± 2	For convention reflow soldering furnace
			(3 times)
8	Substrate bending	No peeling-off at a soldered	Bend width reaches 3 mm and hold for
		part	$5 \text{ s} \pm 1 \text{ s} \times 1 \text{ time Ref. IEC } 60068-2-21$
9	Shear	No peeling-off at a soldered	10 N press for $10 \text{ s} \pm 1 \text{ s}$
		part	Ref. IEC 60068-2-21
10	Pull – off	No peeling-off at a soldered	10 N press for 10 s \pm 1 s
		part	Ref. IEC 60068-2-21
11	Solder ability	Terminals must be 95 %	Dip termination into solder bath at
		covered	$+235$ °C \pm 10 °C for 5 s
. NT		With fresh solder.	(Using Rosin Flux)

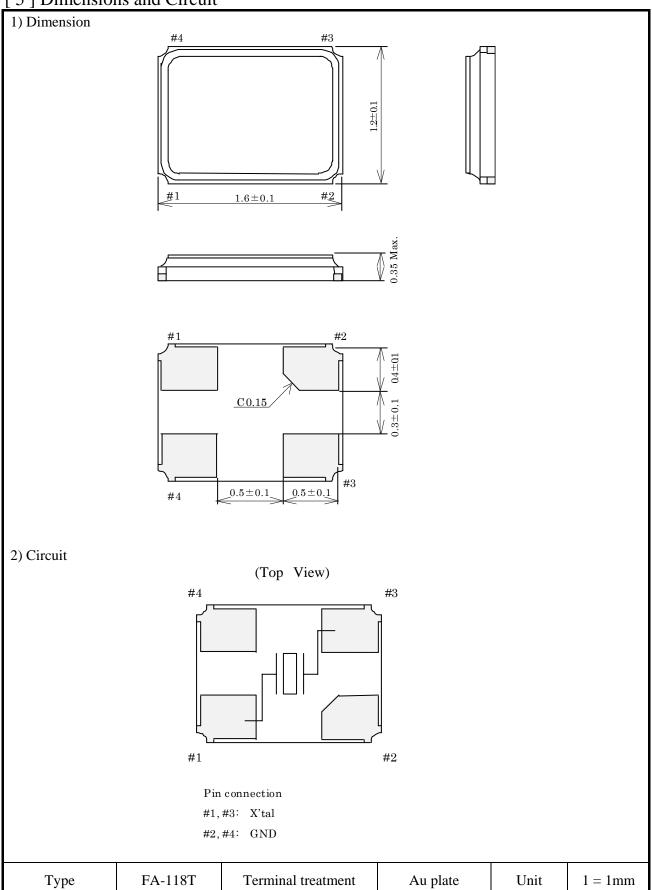
< Notes >

- 1. *1 each test done independently.
- 2. *2 measuring 2 h to 24 h later leaving in room temperature after each test.
- 3. *3 Item No.1 to No.6 shall be tested after following pre conditioning.
- 4. Item No.1 to No.11 resistance at before above tests should be less than ± 20 % or less than ± 10 Ω .
- 5. Pre conditioning: Test crystal must be leaving in room temperature for 24h after reflow \times 3.

Temperature [°C]



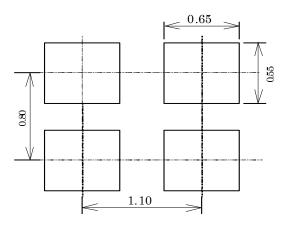
[5] Dimensions and Circuit



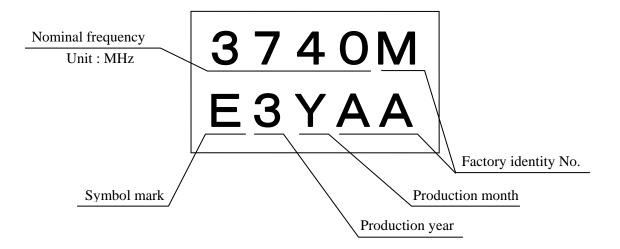
[6] Recommended soldering pattern and Marking layout

1)Recommended soldering pattern

Unit: mm



2) Marking layout



Production month

January	February	 October	November	December
1	2	 X	Y	Z

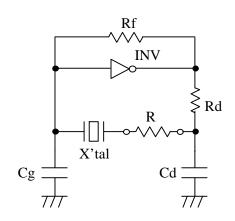
- Nominal frequency is only one example.
- Nominal frequency omits the figure below the second place of decimals. ex) 37.4 MHz [3740]
- The above marking layout shows only marking contents and their approximate position and it is not for font, size and exact position.

Type: FA-118T	Unit : 1 = 1mm

[7] Notes

- 1. Max three (3) times re-flow is allowed. Its recommended to manually solder when not enough/no solder detected.(Using soldering iron at +350 °C × within 3 seconds)
- 2. Patterning on a board should follow our company recommended pattern.
- 3. Applying excessive excitation force to the crystal unit may cause deterioration damage.
- 4. Start up time of oscillation may be increased or no oscillation may occur unless adequate negative resistance is allocated in the oscillation circuit In order to avoid this, please provide enough negative resistance to the circuit design.

How to check the negative resistance



- (1) Connect the resister(R) to the circuit in series with the crystal
- (2) Adjust R so that oscillation can start (or stop).
- (3) Measure R when oscillation just start (or stop) in above (2).
- (4) Get the negative resistance -R=R+CI value.
- (5) Recommended -R $[-R]>CI \times 5$
- 5. It is recommended to do patterning to the oscillator as short as possible. Abnormal oscillation may happened if the line is too long.
- 6. To avoid malfunction, no pattern across or near the crystal unit is allowed.
- 7. Few data or readings taken at user side may be different from our company's data. Confirmation of the different value is necessary before application.
- 8. Too much exciting shock or vibration may cause deterioration on damage.

 The product may damage depends on the condition such as a shock in assembly machinery.

 Please check your process condition in advance to minimize and maintain the shock level.
- 9. This product may be affected to ultrasonic cleaning. It is depends on the cleaning conditions (Cleaning machine type/power/time/content/position etc.). The warranty will not cover any damage due to this type of usage. Check conditions prior to use.
- 10. Condensation may occur when used/stored under high humidity condition. Please take precautions to prevent condensation.
- 11. Please refer to packing specification for the storage method and packing standard.

TAPING SPECIFICATION

1. APPLICATION

This document is applicable to FA-118T

2. CONTENTS

Item No.	Item	Page
[1]	Taping specification	1 to 2
[2]	Inner carton	3
[3]	Shipping carton	3
[4]	Marking	
[5]	Quantity	4
[6]	Storage environment	4
[7]	Handling	

[1] Taping specification

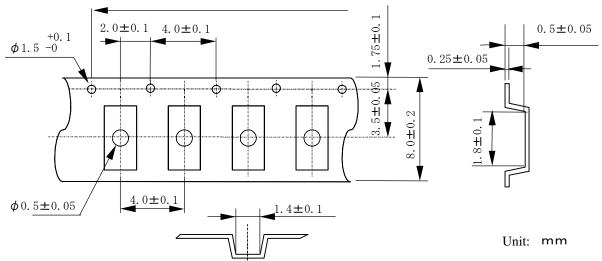
Subject to EIA-481 & IEC-60286

(1) Tape dimensions TE0804L

Material of the Carrier Tape : PS

Material of the Top Tape : PET+PE

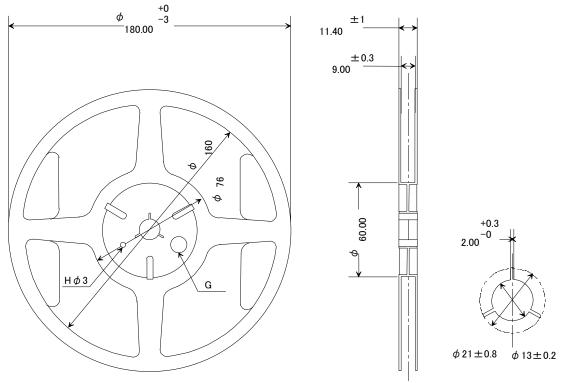
 $10P: 40\pm 0.15$



(2) Reel dimensions

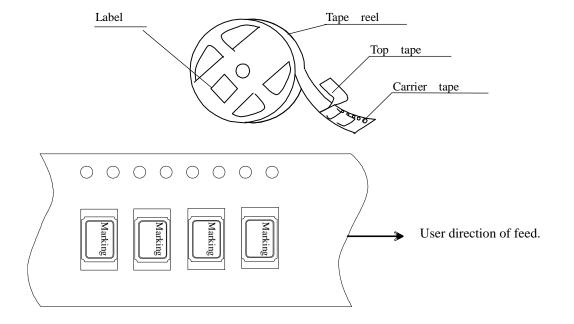
(a) Center material : PS

(b) Material of the Reel : PS

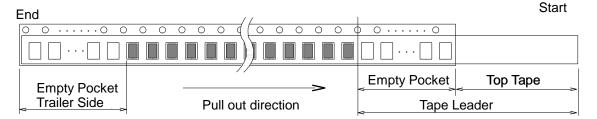


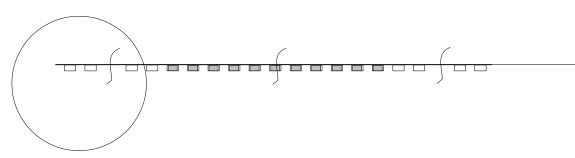
(3) Packing

(a) Tape & Reel



(b) Start & End Point





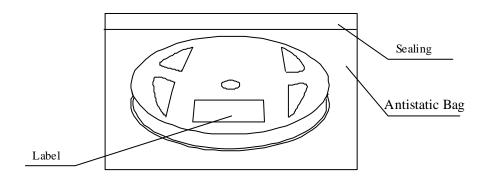
It	Empty Space	
Tape Leader Top Tape		Min. 1 000 mm
	Carrier Tape	Min. 100 mm
Tape Trailer Top Tape		Min. 0 mm
	Carrier Tape	Min. 160 mm

(4) Peel force of the cover tape

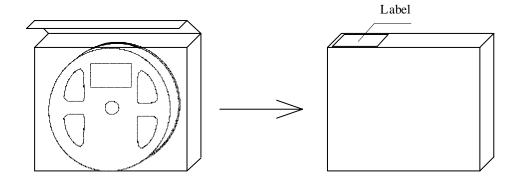
- \bigcirc angle : cover tape during peel off and the direction of unreeling shall be 165° to 180°.
- ② peel speed: 300 mm / min.
- 3 strength : 0.1 to 1 N.

[2] Inner Carton

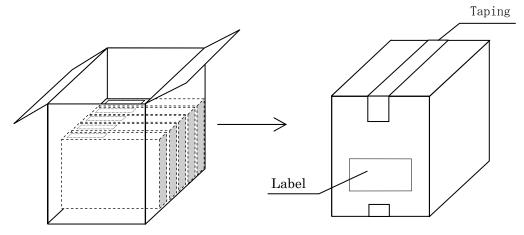
a) Packing to antistatic bag



b) Packing to inner carton



[3] Shipping Carton



[4] Marking

- (1) Reel marking
 - Reel marking shall consist of:
 - 1) Parts name
 - 2) Quantity
 - 3) Manufacturing Date or symbol
 - 4) Manufacturer's Date or symbol
 - 5) Others (if necessary)
- (2) Inner carton marking
 - Same as Reel marking.
- (3) Shipping carton marking
 - Shipping carton marking shall consist of :
 - 1) Parts name
 - 2) Quantity

[5] Quantity

• 6 000 pcs./reel

[6] Storage environment

- (1) Before open the packing, we recommend to keep less than +30 °C and 85 %RH of Humidity, and to use it less than 6 months after delivery.
- (2) We recommend to open Package in immediately before use. After open Package, We recommend to keeps less than 6 month. No need dry air before soldering work if it is less than temperature +30 °C, 85 humidity %RH.
- (3) Not to expose the sun.
- (4) Not to storage with some erosive chemicals.
- (5) Nothing is allowed to put on the reel or carton to prevent mechanical damage.

[7] Handling

To handle with care to prevent the damage of tape, reel and products.

SMD TYPE AT STRIP CRYSTAL : FA-118T

No. A-1003-01-AAE-3

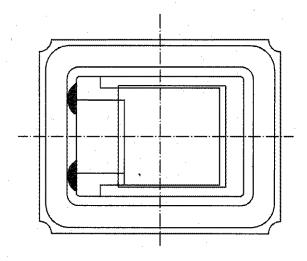
Manufac	turing	process chart	No.	Section	Standard	Inspection, Control items	Inspection method	Instrument	Record
	rystal l	•	1	Inspecting section.	Purchasing specification	Size.	Sampling.	Measure.	In-coming inspection
	Y			(Ina / Miyazaki Plant)	Incoming inspection standard	Outer appearance.	"	Visual inspection.	data sheet.
						Inner appearance.	н	Visual inspection.	
	\bigcirc	Incoming inspection	1'	Inspecting section.	И	Size.	Sampling.	Comparator.	"
				(Ina / Thailand / Malaysia Plant)		Outer appearance.	"	Micro scope.	
	2	Wafer cutting	2	Inspecting section.	Manufacturing instruction sheet	Cut angle.	Sampling.	X-ray raido graphic.	Process data sheet.
				(Ina / Miyazaki Plant)		Wafer thickness.	Н	Comparator.	
ramic base	(3)	Wafer lapping	3	Production section.	И	Frequency.	Sampling.	Frequency counter.	#
1 Incoming				(Ina / Miyazaki Plant)		Wafer thickness.	"	Comparator.	
inspection	4	Photo process	4	Production section.	н	Size.	Sampling.	Comparator.	"
				(Ina / Miyazaki Plant)		Frequency.	"	Frequency counter.	
	_					Outer appearance.	H .	Micro scope.	
Lid	(5)	Mounting	5	Production section.	И	Outer appearance.	All inspecion.	Micro scope.	"
∇				(Ina / Thailand / Malaysia Plant)					
Incoming	6	Frequency adjustment	6	Production section.	И	Frequency.	Sampling.	Network analyzer.	"
1> inspection				(Ina / Thailand / Malaysia Plant)					
	\dashv		7	Production section.	И	Outer appearance.	Sampling.	Micro scope.	#
	7	Welding		(Ina / Thailand / Malaysia Plant)					
	\bot		8	Production section.	н	Airtightness check.	All inspecion.	Leak tester.	"
	\bigcirc	Leak test		(Ina / Thailand / Malaysia Plant)					
			9	Production section.	п	Outer appearance.	Sampling.	Micro scope.	#
	9	Marking		(Ina / Thailand / Malaysia Plant)					
	\perp		10	Production section.	H .	Crystal impedance.	All inspecion.	Inspection M/C.	"
	\bigcirc	Characteristic inspection		(Ina / Thailand / Malaysia Plant)		Frequency.	"	#	
						Insulation resistance.	#	#	
						Temp. characteristic.	Sampling.	"	
	\bot								
		Out-going inspection	11	Inspecting section.	Out-going inspection standard	Crystal impedance.	Sampling.	Inspection M/C.	Out-going inspection
				(Ina / Thailand / Malaysia Plant)		Frequency.	"	"	data sheet.
						Insulation resistance.	"	"	
	 12	Toning	10	Producing section.	Manufacturing instruction sheet	Tape-peel strength.	Sampling.	D	Process data sheet.
		Taping	12	(Ina / Thailand / Malaysia Plant)	Manufacturing instruction sheet	r ape-peer strength.	Sampling.	Peeling force tester.	Process data sneet.
	(13)	Packing	13	Production control section.	Manufacturing instruction sheet	Address.			Delivery slip.
			'	(Ina / Thailand / Malaysia Plant)	Packing instruction sheet	Quantity.	_	l _	Donvory onp.
				,					

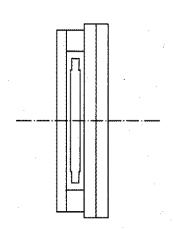
12.09.14

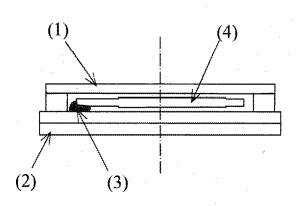
FA-118T Construction Drawing

No.: A-1003-AE-1









No	Parts Name	Material	Surface Treatment
(1)	LID	Covar	Ni Plating
(2)	BASE	Ceramic/ Covar	Au Plating
(3)	Conductive adhesive	Ag Paste	
(4)	Crystal Chip	Crystal	Electrode Pattern (Cr+Au)

RELIABILITY TEST DATA

Product Name: FA-118T

The Company evaluation condition

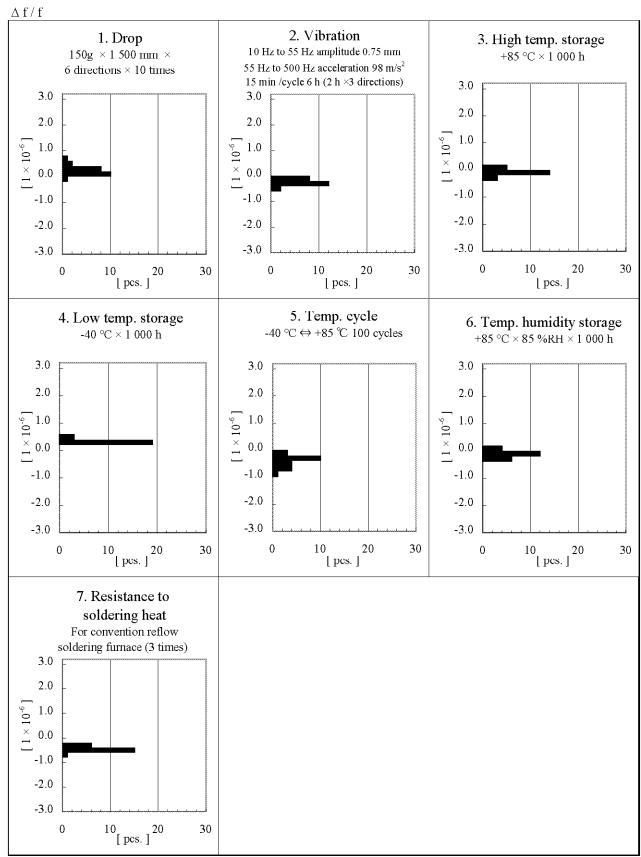
We evaluate environmental and mechanical characteristics by the following test condition.

		and mechanical characteristics by the following	VALUE *1 *2	TEST	FAIL
No.	ITEM	TEST CONDITIONS	Δ f / f	Qty	Qty
			$[1 \times 10^{-6}]$	[n]	[n]
1	Drop	150g dummy Jig (Epsontoyocom Standard) drop from 1500 mm height on the Concrete 6 directions 10 times	*3 ± 2	22	0
2	Vibration	10 Hz to 55 Hz amplitude 0.75 mm 55 Hz to 500 Hz acceleration 98 m/s ² $10 \text{ Hz} \rightarrow 500 \text{ Hz} \rightarrow 10 \text{ Hz}$ 15 min / cycle 6 h (2 h × 3 directions)	*3 ± 2	22	0
3	High temperature storage	+85 °C × 1 000 h	± 2	22	0
4	Low temperature storage	-40 °C × 1 000 h	*3 ± 2	22	0
5	Temperature cycle	-40 °C ⇔ + 85 °C 30 minutes at each temp. 100 cycles	*3 ± 2	22	0
6	Temperature humidity storage	+85 °C × 85 %RH × 1 000 h	± 2	22	0
7	Resistance to soldering heat	For convention reflow soldering furnace (3 times)	± 2	22	0
8	Substrate bending	Bend width reaches 3.0 mm and hold for $5 \text{ s} \pm 1 \text{ s} \times 1$ time Ref. IEC 60068-2-21	No peeling - off at a solder part	11	0
9	Shear	10 N press for 10 s ± 1 s Ref. IEC 60068-2-21	No peeling - off at a solder part	11	0
10	Pull - off	10 N press for 10 s ± 1 s Ref. IEC 60068-2-21	No peeling - off at a solder part	11	0
11	Solderability	Dip termination into solder bath at +235°C ± 10 °C for 5 s (Using Rosin Flux)	Termination must be 95 % covered with fresh solder	11	0

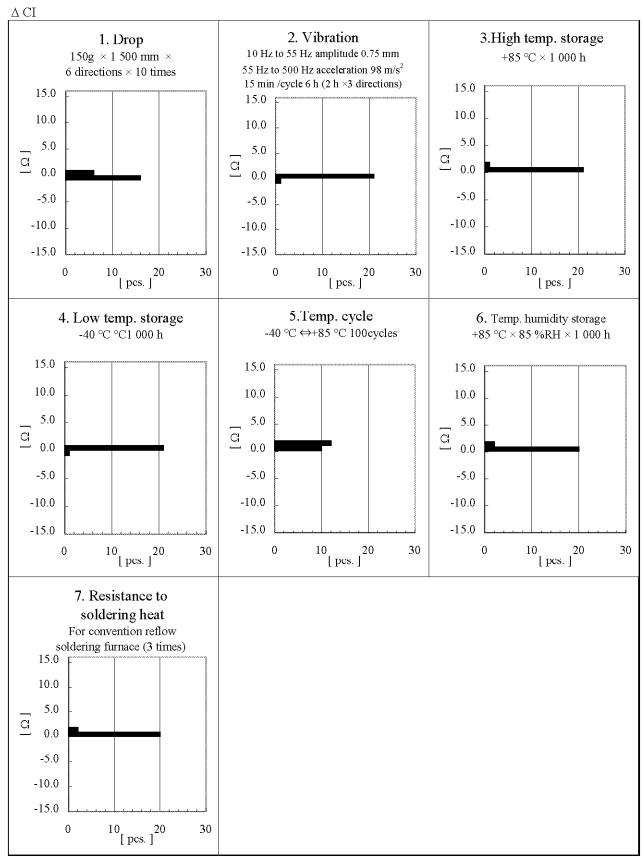
Notes

- 1. *1 Each test done independently.
- 2. *2 Measuring 2 h to 24 h later leaving in room temperature after each test.
- 3. *3 Measuring 24 h later leaving in room temperature after each test.
 - 1. Reflow 3 times
 - 2. Initial value shall be after 24h at room temperature.
- 4. Shift series resistance at before above tests should be less than ± 20 % or less than ± 10 Ω .

Product Name: FA-118T



Product Name: FA-118T





ATTN: SZ TINNO MOBILE TECH CO. LTD

Quality and reliability data

No.ST13-398 Nov., 26, 2013 SEIKO EPSON CORP. TD • CS QUALITY ASSURANCE DEPARTMENT

Type: FA-118T

·Machine Model JEDEC JESD22-A115-A

 $(C=200 \text{ pF}; R=0 \Omega)$: > ±200 Volt

·Human Body Model JESD22-A114-D

 $(C=100 \text{ pF}; R=1 500 \Omega)$: > ±2 000 Volt

Criterion : Frequency change rate exceeded $\pm 2 \times 10^{-6}$ or Oscillation stopped as Failure.